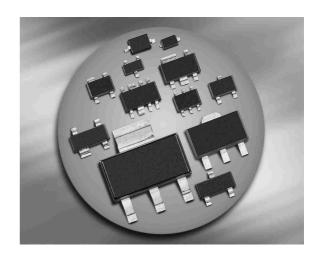


#### **Silicon Schottky Diode**

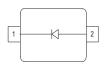
- Low barrier diode for detectors up to GHz frequencies
- For high-speed applications
- Zero bias detector diode
- Pb-free (RoHS compliant) package





#### BAT63-02V

**BAT63-07W** 





## ESD (Electrostatic discharge) sensitive device, observe handling precaution!

Туре	Package	Configuration	<b>L</b> <sub>S</sub> (nH)	Marking
BAT63-02V	SC79	single	0.6	d
BAT63-07W	SOT343	parallel pair	1.6	63s

## **Maximum Ratings** at $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	$V_{R}$	3	V
Forward current	I <sub>F</sub>	100	mA
Total power dissipation	P <sub>tot</sub>		mW
<i>T</i> <sub>S</sub> ≤ 120°C, BAT63-02V		100	
<i>T</i> <sub>S</sub> ≤ 114°C, BAT63-07W		100	
Junction temperature	T <sub>i</sub>	150	°C
Storage temperature	T <sub>stg</sub>	-55 150	

#### **Thermal Resistance**

Parameter	Symbol	Value	Unit
Junction - soldering point <sup>1)</sup>	R <sub>thJS</sub>		K/W
BAT63-02V		≤ 295	
BAT63-07W		≤ 355	



## **Electrical Characteristics** at $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol		Values		
		min.	typ.	max.	
DC Characteristics					•
Reverse current	$I_{R}$	-	-	10	μA
V <sub>R</sub> = 3 V					
Forward voltage	$V_{F}$	-	190	300	mV
<i>I</i> <sub>F</sub> = 1 mA					
Forward voltage matching <sup>2)</sup>	ΔV <sub>F</sub>	-	-	20	
<i>I</i> <sub>F</sub> = 1 mA					
AC Characteristics					
Diode capacitance	C <sub>T</sub>	-	0.65	0.85	pF
$V_{R}$ = 0.2 V, $f$ = 1 MHz					
Differential resistance	$R_0$	-	30	-	kΩ
$V_{R} = 0$ , $f = 10 \text{ kHz}$					

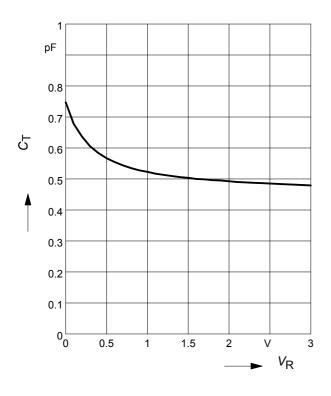
 $<sup>^{1}\</sup>mbox{For calculation of}\ R_{\mbox{\scriptsize thJA}}$  please refer to Application Note Thermal Resistance

 $<sup>^2\</sup>Delta V_{\mathrm{F}}$  is the difference between lowest and highest  $V_{\mathrm{F}}$  in a multiple diode component.



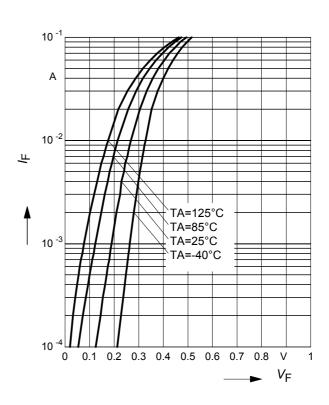
## **Diode capacitance** $C_T = f(V_R)$

f = 1MHz



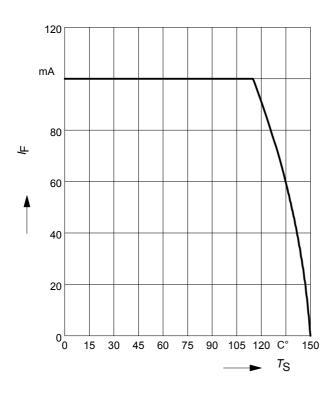
## Forward current $I_F = f(V_F)$

 $T_A$  = Parameter



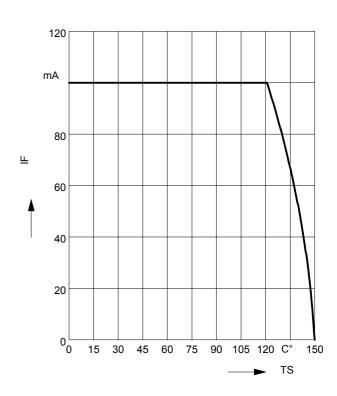
## Forward current $I_F = f(T_S)$

BAT63-07W



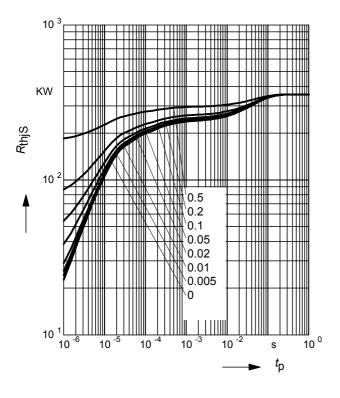
## Forward current $I_F = f(T_S)$

BAT63-02V



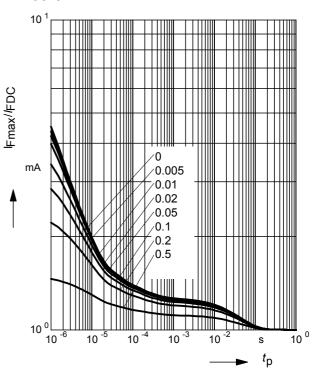


# **Permissible Puls Load** $R_{thJS} = f(t_p)$ BAT63-07W

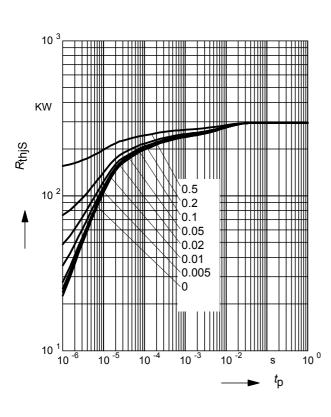


#### **Permissible Pulse Load**

 $I_{\text{Fmax}}/I_{\text{FDC}} = f(t_{\text{p}})$ BAT63-07W

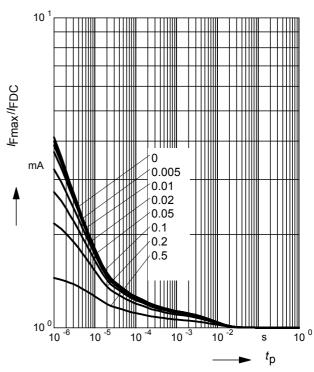


# **Permissible Pulse Load** $R_{thJS} = f(t_p)$ BAT63-02V



#### **Permissible Pulse Load**

 $I_{\text{Fmax}}/I_{\text{FDC}} = f(t_{\text{p}})$ BAT63-02V

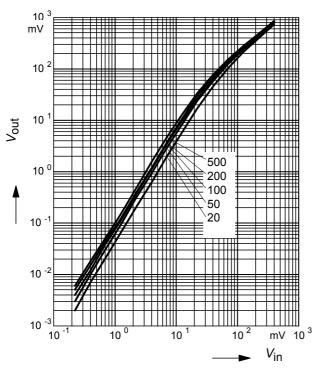




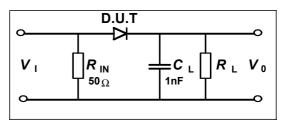
## Rectifier voltage $V_{out} = f(V_{in})$

*f* = 2.4GHz

 $R_{\mathsf{L}}$  = Parameter in  $k\Omega$ 



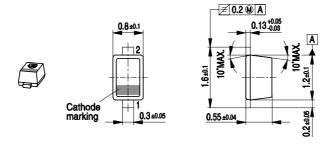
## Testcircuit



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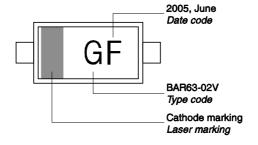
## Package Outline



#### **Foot Print**



## Marking Layout (Example)

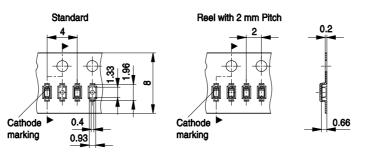


## Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel

Reel ø180 mm = 8.000 Pieces/Reel (2 mm Pitch)

Reel ø330 mm = 10.000 Pieces/Reel





# Date Code marking for discrete packages with one digit (SCD80, SC79, SC751) CES-Code

Month	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014
01	а	р	Α	Р	а	р	Α	Р	а	р	Α	Р
02	b	q	В	Q	b	q	В	Q	b	q	В	Q
03	С	r	С	R	С	r	С	R	С	r	С	R
04	d	S	D	S	d	S	D	S	d	s	D	S
05	е	t	Е	Τ	е	t	Е	Т	е	t	Е	Т
06	f	u	F	U	f	u	F	U	f	u	F	U
07	g	٧	G	V	g	٧	G	V	g	٧	G	V
08	h	Х	Н	Х	h	Х	Н	Χ	h	Х	Н	Х
09	j	У	J	Υ	j	у	J	Υ	j	У	J	Y
10	k	Z	K	Z	k	Z	K	Z	k	Z	K	Z
11	I	2	L	4	I	2	L	4	I	2	L	4
12	n	3	N	5	n	3	N	5	n	3	N	5

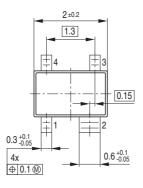
<sup>1)</sup> New Marking Layout for SC75, implemented at October 2005.

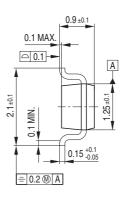
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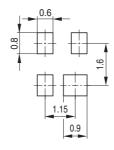
## Package Outline



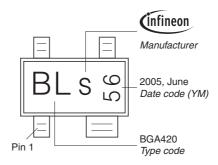




#### Foot Print

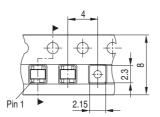


## Marking Layout (Example)



## Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel







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